

## 2STX1360

## LOW VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

#### **Features**

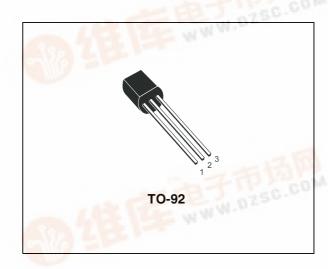
- VERY LOW COLLECTOR-EMITTER SATUARATION VOLTAGE
- HIGH CURRENT GAIN CHARACTERISTIC
- FAST-SWITCHING SPEED
- IN COMPLANCE WITH THE 2002/93/EC **EUROPEAN DIRECTIVE**

### **Applications**

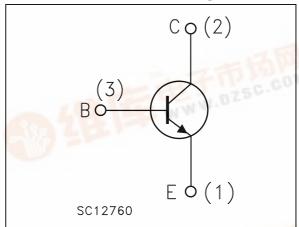
- **■** EMERGENCY LIGHTING
- CCFL DRIVERS (BACK LIGHTING)
- **VOLTAGE REGULATION** WWW.DZSC.COM
- RELAY DRIVER

### **Description**

The 2STX1360 is a NPN transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.



### **Internal Schematic Diagram**



#### **Order Codes**

Part Number	Marking	Package	Packing
2STX1360	X1360	TO-92	Bulk



# 1 Absolute Maximum Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage (I <sub>B</sub> = 0)	60	V
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	6	V
I <sub>C</sub>	Collector Current	3	Α
I <sub>CM</sub>	Collector Peak Current (t <sub>P</sub> < 5ms)	5	Α
I <sub>B</sub>	Base Current	0.2	Α
I <sub>BM</sub>	Base Peak Current (t <sub>P</sub> < 5ms)	0.4	Α
P <sub>TOT</sub>	Total dissipation at T <sub>C</sub> = 25°C	1	W
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
T <sub>J</sub>	Max. Operating Junction Temperature	150	°C

Table 2. Thermal Data

Symbol	Parameter		Value	Unit
R <sub>thJ-case</sub>	Thermal Resistance Junction-Case	Max	44.6	°C/W
R <sub>thJ-amb</sub>	Thermal Resistance Junction-Ambient	Max	125	°C/W

**2STX1360** 2 Electrical Characteristics

## **2 Electrical Characteristics**

Table 3. Electrical Characteristics ( $T_{CASE} = 25^{\circ}C$ ; unless otherwise specified)

Symbol	Parameter	Test Co	onditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector Cut-off Current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 80 V				100	nA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 6 V				100	nA
V <sub>BE</sub>	Base-Emitter Voltage	V <sub>CE</sub> = 2 V	I <sub>C</sub> = 100 mA	630	670	730	mV
V <sub>CE(sat)</sub> Note: 1	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2 A I <sub>C</sub> = 3 A	I <sub>B</sub> = 100 mA I <sub>B</sub> = 150 mA		150 210	300 500	mV mV
V <sub>BE(sat)</sub> Note: 1	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2 A	I <sub>B</sub> = 100 mA		0.89	1.2	V
h <sub>FE</sub> Note: 1	DC Current Gain	$I_C = 100 \text{ mA}$ $I_C = 1 \text{ A}$		80 160	280	400	
t <sub>d</sub> t <sub>r</sub> t <sub>s</sub>	RESISTIVE LOAD Delay Time Rise Time Storage Time Fall Time	$V_{CC} = 10 \text{ V}$ $I_{B1} = -I_{B2} = 30$ (see figure 8)	-		17 81 620 54	20 100 720 65	ns ns ns
f <sub>T</sub>	Transition Frequency	I <sub>C</sub> = 0.1 A	V <sub>CE</sub> = 10 V		130		MHz

Note: 1 Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$ 1.5%.

2 Electrical Characteristics 2STX1360

### 2.1 Typical Characteristics

Figure 1. DC Current Gain

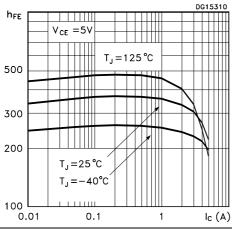


Figure 2. DC Current Gain

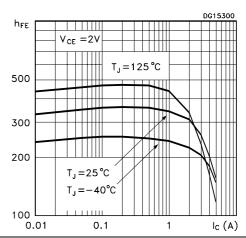
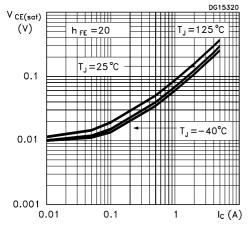


Figure 3. Collector Emitter Saturation Voltage Figure 4. Base Emitter Saturation Voltage



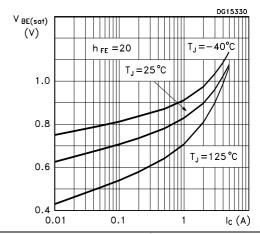
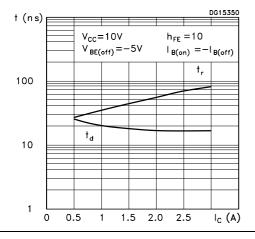
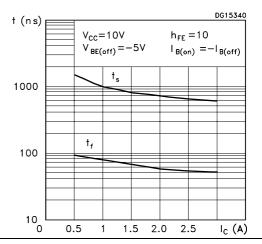


Figure 5. Resistive Load Switching Times

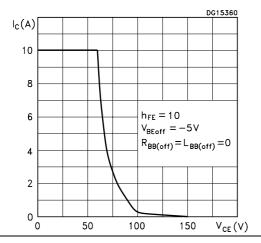
Figure 6. Resistive LoadSwitching Times





**2STX1360** 2 Electrical Characteristics

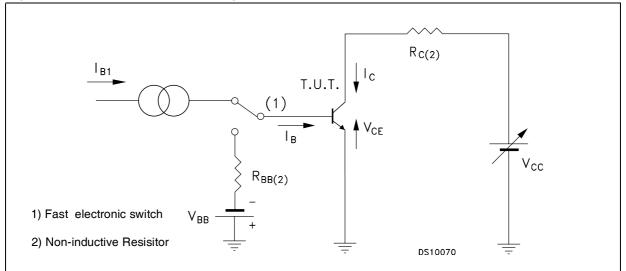
Figure 7. Reverse Bised SOA



3 Test Circuits 2STX1360

## 3 Test Circuits

Figure 8. Resistive Load Switching Test Circuit



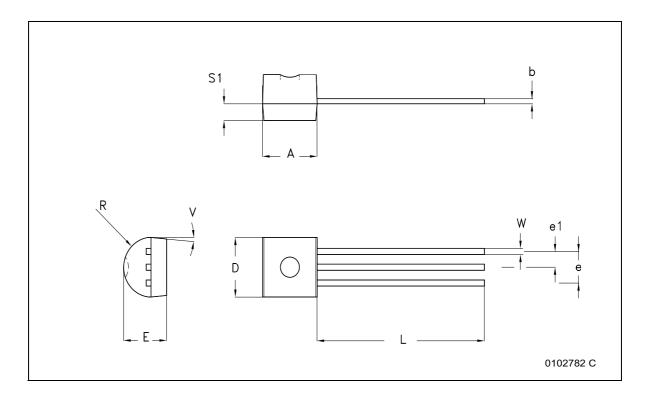
# 4 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>



#### **TO-92 BULK SHIPMENT MECHANICAL DATA**

DIM.	mm.			
	MIN.	ТҮР	MAX.	
А	4.32		4.95	
b	0.36		0.51	
D	4.45		4.95	
Е	3.30		3.94	
е	2.41		2.67	
e1	1.14		1.40	
L	12.70		15.49	
R	2.16		2.41	
S1	0.92		1.52	
W	0.41		0.56	
V		5 <sup>O</sup>		



2STX1360 5 Revision History

# 5 Revision History

Date	Revision	Changes
17-Nov-2005	1	Initial Release

5 Revision History 2STX1360

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